NSN 5962-01-076-6627

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-076-6627 **Body Length:** 0.440 inches **Body Width:** Between 0.240 inches and 0.325 inches **Body Height:** 0.085 inches **Maximum Power Dissipation Rating:** 910.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and monolithic and positive outputs and w/storage and programmable and programmed and bipolar and 3-state output and schottky and high speed and expandable and w/buffered output and w/decoded output and w/enable and w/disable **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Flat pack **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 10 input **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** 5.5 volts power source **Time Rating Per Chacteristic:** 75.00 nanoseconds propagation delay time, low to high level output **Memory Device Type:** Rom **Test Data Document:** 82577-932820 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 16 flat leads Shelf Life: N/a **Unit Of Measure:**

Fiig:

A458a0

Demilitarization: Yes - demil/mli